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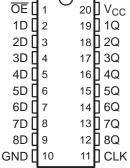
SCAS715B-SEPTEMBER 2003-REVISED APRIL 2008

# OCTAL EDGE-TRIGGERED D-TYPE FLIP-FLOP **WITH 3-STATE OUTPUTS**

### **FEATURES**

- **Qualified for Automotive Applications**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Operates From 2 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>pd</sub> of 7 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) < 0.8 V at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) > 2 V at  $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- **Supports Mixed-Mode Signal Operation on All** Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation

#### **DW OR PW PACKAGE** (TOP VIEW) OE [] 1 1D 🛮 2 19**∏** 1Q 2D 🛮 3 18 2Q



#### DESCRIPTION/ORDERING INFORMATION

The SN74LVC574A octal edge-triggered D-type flip-flop is designed for 2.7-V to 3.6-V V<sub>CC</sub> operation.

This device features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. It is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels at the data (D) inputs.

A buffered output-enable (OE) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### ORDERING INFORMATION<sup>(1)</sup>

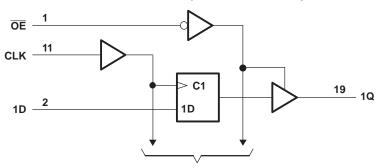
| T <sub>A</sub> | PACKAG     | E <sup>(2)</sup> | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|----------------|------------|------------------|-----------------------|------------------|
| –40°C to 125°C | SOIC - DW  | Reel of 2000     | SN74LVC574AQDWRQ1     | L574AQ1          |
| -40 C to 125 C | TSSOP - PW | Reel of 2000     | SN74LVC574AQPWRQ1     | L574AQ1          |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

# FUNCTION TABLE (EACH FLIP-FLOP)

|    | INPUTS   |   | OUTPUT |
|----|----------|---|--------|
| ŌĒ | CLK      | D | Q      |
| L  | <b>↑</b> | Н | Н      |
| L  | <b>↑</b> | L | L      |
| L  | L        | X | $Q_0$  |
| Н  | X        | X | Z      |

### LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels

# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                  |  |                                 | MIN  | MAX         | UNIT |
|------------------|--|---------------------------------|------|-------------|------|
| $V_{CC}$         | Supply voltage range   |                                 | -0.5 | 6.5         | V    |
| V <sub>I</sub>   | Input voltage range <sup>(2)</sup>   |                                 | -0.5 | 6.5         | V    |
| Vo               | Voltage range applied to any output in the high-in                                 | mpedance or power-off state (2) | -0.5 | 6.5         | V    |
| Vo               | V <sub>O</sub> Voltage range applied to any output in the high or low state (2)(3) |                                 |      |             | V    |
| I <sub>IK</sub>  | Input clamp current  | V <sub>I</sub> < 0              |      | <b>–</b> 50 | mA   |
| I <sub>OK</sub>  | Output clamp current   | V <sub>O</sub> < 0              |      | -50         | mA   |
| Io               | Continuous output current  |                                 |      | ±50         | mA   |
|                  | Continuous current through V <sub>CC</sub> or GND                                  |                                 |      | ±100        | mA   |
| 0                | Package thermal impedance (4)  | DW package                      |      | 58          | °C/W |
| $\theta_{JA}$    | гаскаде шеппантрецапсе <sup>чу</sup>   | PW package                      |      | 83          | C/VV |
| T <sub>stg</sub> | Storage temperature range  | -65                             | 150  | °C          |      |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

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# Recommended Operating Conditions<sup>(1)</sup>

|                 |   |                                  | MIN | MAX      | UNIT |
|-----------------|---|----------------------------------|-----|----------|------|
| \/              | Cumply valtage                            | Operating                        | 2   | 3.6      | V    |
| V <sub>CC</sub> | Supply voltage                            | Data retention only              | 1.5 |          | V    |
| V <sub>IH</sub> | High-level input voltage                  | V <sub>CC</sub> = 2.7 V to 3.6 V | 2   |          | V    |
| V <sub>IL</sub> | Low-level input voltage                   | V <sub>CC</sub> = 2.7 V to 3.6 V |     | 0.8      | V    |
| VI              | Input voltage                             | •                                | 0   | 5.5      | V    |
|                 | Outrout valte as                          | High or low state                | 0   | $V_{CC}$ | V    |
| Vo              | Output voltage                            | 3-state                          | 0   | 5.5      | V    |
| -               | High level evitevit evinent               | V <sub>CC</sub> = 2.7 V          |     | -12      | A    |
| I <sub>OH</sub> | High-level output current                 | V <sub>CC</sub> = 3 V            |     | -24      | mA   |
|                 | Law l | V <sub>CC</sub> = 2.7 V          |     | 12       | 1    |
| I <sub>OL</sub> | Low-level output current                  | V <sub>CC</sub> = 3 V            |     | 24       | mA   |
| Δt/Δν           | Input transition rise or fall rate        | Ţ                                |     | 6        | ns/V |
| T <sub>A</sub>  | Operating free-air temperature            |                                  | -40 | 125      | °C   |

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER       | TEST C   | ONDITIONS  | V <sub>CC</sub> | MIN            | TYP <sup>(1)</sup> MAX | UNIT |
|-----------------|--|--|-----------------|----------------|------------------------|------|
|                 | $I_{OH} = -100 \mu A$                                  |  | 2.7 V to 3.6 V  | $V_{CC} - 0.2$ |                        |      |
| V               | I <sub>OH</sub> = -12 mA                               |  | 2.7 V           | 2.2            |                        | V    |
| V <sub>OH</sub> | IOH = -12 IIIA   |  | 3 V             | 2.4            |                        | ٧    |
|                 | $I_{OH} = -24 \text{ mA}$                              |  | 3 V             | 2.2            |                        |      |
|                 | $I_{OL} = 100 \mu A$                                   |  | 2.7 V to 3.6 V  |                | 0.2                    |      |
| $V_{OL}$        | I <sub>OL</sub> = 12 mA                                |  | 2.7 V           |                | 0.4                    | V    |
|                 | I <sub>OL</sub> = 24 mA                                |  | 3 V             |                | 0.55                   |      |
| I <sub>I</sub>  | $V_1 = 0 \text{ to } 5.5 \text{ V}$                    |  | 3.6 V           |                | ±5                     | μΑ   |
| I <sub>OZ</sub> | $V_0 = 0 \text{ to } 5.5 \text{ V}$                    |  | 3.6 V           |                | ±15                    | μΑ   |
|                 | $V_I = V_{CC}$ or GND                                  | 1 -0   | 3.6 V           |                | 10                     | ^    |
| I <sub>CC</sub> | $3.6 \text{ V} \le \text{V}_1 \le 5.5 \text{ V}^{(2)}$ | $I_0 = 0$  | 3.0 V           |                | 10                     | μΑ   |
| $\Delta I_{CC}$ | One input at $V_{CC} - 0.6 V$ ,                        | <ul><li>– 0.6 V, Other inputs at V<sub>CC</sub> or GND</li></ul> |                 |                | 500                    | μΑ   |
| C <sub>i</sub>  | $V_I = V_{CC}$ or GND                                  | 3.3 V  |                 | 4              | pF                     |      |
| C <sub>o</sub>  | $V_O = V_{CC}$ or GND                                  |  | 3.3 V           |                | 5.5                    | pF   |

<sup>(1)</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

|                    |                                 | V <sub>CC</sub> = 2.7 V |     | V <sub>CC</sub> = 3<br>± 0.3 | UNIT |     |
|--------------------|---------------------------------|-------------------------|-----|------------------------------|------|-----|
|                    |                                 | MIN                     | MAX | MIN                          | MAX  |     |
| f <sub>clock</sub> | Clock frequency                 |                         | 150 |                              | 150  | MHz |
| t <sub>w</sub>     | Pulse duration, CLK high or low | 3.3                     |     | 3.3                          |      | ns  |
| t <sub>su</sub>    | Setup time, data before CLK↑    | 2                       |     | 2                            |      | ns  |
| t <sub>h</sub>     | Hold time, data after CLK↑      | 2                       |     | 2                            |      | ns  |

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<sup>(2)</sup> This applies in the disabled state only.



### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| PARAMETER        | FROM    | TO<br>(OUTPUT) | V <sub>CC</sub> = | 2.7 V | V <sub>CC</sub> = 0.3 | 3.3 V<br>3 V | UNIT |
|------------------|---------|----------------|-------------------|-------|-----------------------|--------------|------|
|                  | (INPUT) | (001701)       | MIN               | MAX   | MIN                   | MAX          |      |
| f <sub>max</sub> |         |                | 150               |       | 150                   |              | MHz  |
| t <sub>pd</sub>  | CLK     | Q              |                   | 8     | 1                     | 7            | ns   |
| t <sub>en</sub>  | ŌĒ      | Q              |                   | 9     | 1                     | 7.5          | ns   |
| t <sub>dis</sub> | ŌĒ      | Q              |                   | 7     | 0.5                   | 6.4          | ns   |

# **Operating Characteristics**

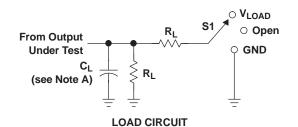
 $T_A = 25^{\circ}C$ 

|          | PARAMETER                                   | TEST<br>CONDITIONS | V <sub>CC</sub> = 2.5 V<br>TYP | V <sub>CC</sub> = 3.3 V<br>TYP | UNIT |    |  |
|----------|---|--------------------|--------------------------------|--------------------------------|------|----|--|
|          | Dower discination conscitance per flip flop | Outputs enabled    | f 40 MHz                       | 60                             | 43   | ~F |  |
| $C_{pd}$ | Power dissipation capacitance per flip-flop | Outputs disabled   | f = 10 MHz                     | 9                              | 15   | pF |  |

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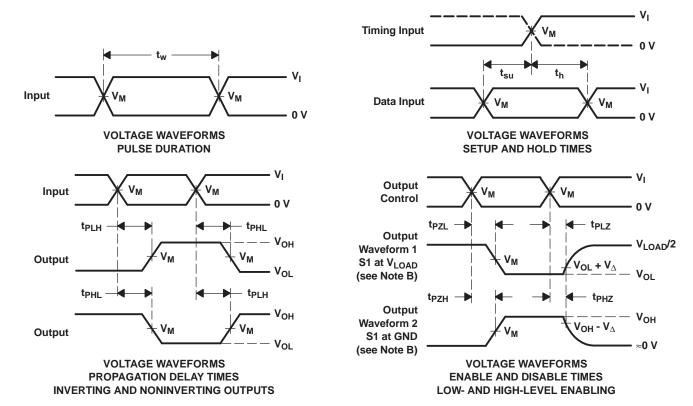


#### PARAMETER MEASUREMENT INFORMATION



| TEST   | S1                               |
|--|----------------------------------|
| t <sub>PLH</sub> /t <sub>PHL</sub> t <sub>PLZ</sub> /t <sub>PZL</sub> t <sub>PHZ</sub> /t <sub>PZH</sub> | Open<br>V <sub>LOAD</sub><br>GND |

| .,              | INF   | PUTS                           | .,             | V                 | _              | -            | V                     |
|-----------------|-------|--------------------------------|----------------|-------------------|----------------|--------------|-----------------------|
| V <sub>CC</sub> | VI    | t <sub>r</sub> /t <sub>f</sub> | V <sub>M</sub> | V <sub>LOAD</sub> | C <sub>L</sub> | $R_L$        | $oldsymbol{V}_\Delta$ |
| 2.7 V           | 2.7 V | ≤2.5 ns                        | 1.5 V          | 6 V               | 50 pF          | 500 Ω        | 0.3 V                 |
| 3.3 V ± 0.3 V   | 2.7 V | ≤2.5 ns                        | 1.5 V          | 6 V               | 50 pF          | <b>500</b> Ω | 0.3 V                 |



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



## PACKAGE OPTION ADDENDUM

25-Mar-2015

#### PACKAGING INFORMATION

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| Orderable Device  | Status   | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Device Marking | Samples |
|-------------------|----------|--------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|----------------|---------|
|                   | (1)      |              | Drawing            |      | Qty            | (2)                        | (6)              | (3)                |              | (4/5)          |         |
| CLVC574AQDWRG4Q1  | ACTIVE   | SOIC         | DW                 | 20   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | L574AQ1        | Samples |
| CLVC574AQPWRG4Q1  | ACTIVE   | TSSOP        | PW                 | 20   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | L574AQ1        | Samples |
| SN74LVC574AQDWRQ1 | ACTIVE   | SOIC         | DW                 | 20   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 125   | L574AQ1        | Samples |
| SN74LVC574AQPWRQ1 | OBSOLETE | TSSOP        | PW                 | 20   |                | TBD                        | Call TI          | Call TI            | -40 to 125   |                |         |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



### **PACKAGE OPTION ADDENDUM**

25-Mar-2015

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#### OTHER QUALIFIED VERSIONS OF SN74LVC574A-Q1:

■ Catalog: SN74LVC574A

■ Enhanced Product: SN74LVC574A-EP

Military: SN54LVC574A

NOTE: Qualified Version Definitions:

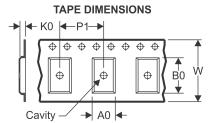
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

# PACKAGE MATERIALS INFORMATION

www.ti.com 20-Dec-2013

### TAPE AND REEL INFORMATION





| Α0 | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device            | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CLVC574AQDWRG4Q1  | SOIC            | DW                 | 20 | 2000 | 330.0                    | 24.4                     | 10.8       | 13.3       | 2.7        | 12.0       | 24.0      | Q1               |
| CLVC574AQPWRG4Q1  | TSSOP           | PW                 | 20 | 2000 | 330.0                    | 16.4                     | 6.95       | 7.1        | 1.6        | 8.0        | 16.0      | Q1               |
| SN74LVC574AQDWRQ1 | SOIC            | DW                 | 20 | 2000 | 330.0                    | 24.4                     | 10.8       | 13.3       | 2.7        | 12.0       | 24.0      | Q1               |

www.ti.com 20-Dec-2013



\*All dimensions are nominal

| Device               | Device Package Type |                 | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm)  |  |
|----------------------|---------------------|-----------------|------|------|-------------|------------|--------------|--|
| 011/05744.0514/50404 | <u> </u>            | Package Drawing | 00   |      | , , ,       | 207.0      | <b>O</b> ( ) |  |
| CLVC574AQDWRG4Q1     | SOIC                | DW              | 20   | 2000 | 367.0       | 367.0      | 45.0         |  |
| CLVC574AQPWRG4Q1     | TSSOP               | PW              | 20   | 2000 | 367.0       | 367.0      | 38.0         |  |
| SN74LVC574AQDWRQ1    | SOIC                | DW              | 20   | 2000 | 367.0       | 367.0      | 45.0         |  |



SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G20)

# PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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